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ISL9V5045S3S / ISL9V5045S3 EcoSPARK® N-Channel Ignition IGBT

500mJ, 450V

Features

- SCIS Energy = 500mJ at T_J = 25°C
- Logic Level Gate Drive

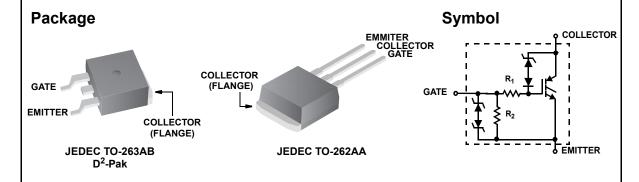
Applications

- Automotive Ignition Coil Driver Circuits
- Coil On Plug Applications

General Description

The ISL9V5045S3S and ISL9V5045S3 are next generation ignition IGBTs that offer outstanding SCIS capability in the industry standard D²-Pak (TO-263) plastic package. This device is intended for use in automotive ignition circuits, specifically as a coil drivers. Internal diodes provide voltage clamping without the need for external components.

EcoSPARK® devices can be custom made to specific clamp voltages. Contact your nearest Fairchild sales office for more information.



Units

Device Maximum Ratings $T_A = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Ratings	Units
BV _{CER}	Collector to Emitter Breakdown Voltage (I _C = 1 mA)	480	V
BV _{ECS}	Emitter to Collector Voltage - Reverse Battery Condition (I _C = 10 mA)	24	V
E _{SCIS25}	At Starting $T_J = 25^{\circ}C$, $I_{SCIS} = 39.2A$, $L = 650 \mu Hy$	500	mJ
E _{SCIS150}	At Starting T_J = 150°C, I_{SCIS} = 31.1A, L = 650 μ Hy	315	mJ
I _{C25}	Collector Current Continuous, At T _C = 25°C, See Fig 9	51	Α
I _{C110}	Collector Current Continuous, At T _C = 110°C, See Fig 9	43	Α
V_{GEM}	Gate to Emitter Voltage Continuous	±10	V
P_{D}	Power Dissipation Total T _C = 25°C	300	W
	Power Dissipation Derating T _C > 25°C	2	W/°C
T_J	Operating Junction Temperature Range	-40 to 175	°C
T _{STG}	Storage Junction Temperature Range	-40 to 175	°C
T _L	Max Lead Temp for Soldering (Leads at 1.6mm from Case for 10s)	300	°C
T _{pkg}	Max Lead Temp for Soldering (Package Body for 10s)	260	°C
ESD	Electrostatic Discharge Voltage at 100pF, 1500Ω	4	kV

Package Marking and Ordering Information

Device Marking	Device Marking Device		Reel Size	Tape Width	Quantity
V5045S	ISL9V5045S3ST	TO-263AB	330mm	24mm	800
V5045S	ISL9V5045S3	TO-262AA	Tube	N/A	50
V5045S	ISL9V5045S3S	TO-263AB	Tube	N/A	50

Test Conditions

Min

Тур

1.25

1.47

1.60

1.80

Max

Electrical Characteristics T_A = 25°C unless otherwise noted

Parameter

Collector to Emitter Saturation Voltage

Collector to Emitter Saturation Voltage

BV _{CER}	Collector to Emitter Breakdown Voltage	I_C = 2mA, V_{GE} = 0, R_G = 1K Ω , See Fig. 15 T_J = -40 to 150°C		420	450	480	V
BV _{CES}	Collector to Emitter Breakdown Voltage	I_C = 10mA, V_{GE} = 0, R_G = 0, See Fig. 15 T_J = -40 to 150°C		445	475	505	V
BV _{ECS}	Emitter to Collector Breakdown Voltage	$I_C = -75 \text{mA}, V_{GE} = 0 \text{V},$ $T_C = 25 ^{\circ} \text{C}$		30	-	-	٧
BV _{GES}	Gate to Emitter Breakdown Voltage	I _{GES} = ± 2mA		±12	±14	-	V
I _{CER}	Collector to Emitter Leakage Current	lector to Emitter Leakage Current $V_{CER} = 320V$, $T_{C} = 25^{\circ}C$		-	-	25	μA
		R_G = 1KΩ, See Fig. 11	T _C = 150°C	-	-	1	mA
I _{ECS}		T _C = 25°C	-	-	1	mA	
		Fig. 11	T _C = 150°C	-	-	40	mA
R ₁	Series Gate Resistance			-	100	-	Ω
R_2	Gate to Emitter Resistance			10K	-	30K	Ω

 $I_{\rm C} = 10A$

I_C = 15A,

 $V_{GE} = 4.0V$

 $V_{GE} = 4.5V$

T_C = 25°C,

See Fig. 4

T_C = 150°C

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On State Characteristics

 $V_{CE(SAT)}$

 $V_{CE(SAT)}$

Symbol

Dynamic Characteristics

Q _{G(ON)}	Gate Charge	$I_C = 10A, V_{CE} = V_{GE} = 5V, See$	= 12V, Fig. 14	-	32	-	nC
V _{GE(TH)}	Gate to Emitter Threshold Voltage	$I_C = 1.0 \text{mA},$	T _C = 25°C	1.3	-	2.2	V
		V _{CE} = V _{GE,} See Fig. 10	T _C = 150°C	0.75	1	1.8	V
V _{GEP}	Gate to Emitter Plateau Voltage	I _C = 10A,	V _{CE} = 12V	-	3.0	-	V

Switching Characteristics

t _{d(ON)R}	Current Turn-On Delay Time-Resistive	V_{CE} = 14V, R_L = 1 Ω ,	-	0.7	4	μs
t _{rR}	Current Rise Time-Resistive	V_{GE} = 5V, R _G = 1KΩ T _J = 25°C, See Fig. 12	-	2.1	7	μs
t _{d(OFF)L}	Current Turn-Off Delay Time-Inductive	$V_{CE} = 300V, L = 2mH,$	-	10.8	15	μs
t _{fL}	Current Fall Time-Inductive	V_{GE} = 5V, R_G = 1K Ω T_J = 25°C, See Fig. 12	-	2.8	15	μs
SCIS	Self Clamped Inductive Switching	T_J = 25°C, L = 650 μH, R_G = 1KΩ, V_{GE} = 5V, See Fig. 1 & 2	-	-	500	mJ

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance Junction-Case	TO-263, TO-262	-	-	0.5	°C/W

Typical Characteristics

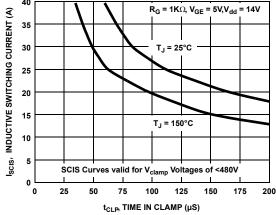


Figure 1. Self Clamped Inductive Switching
Current vs Time in Clamp

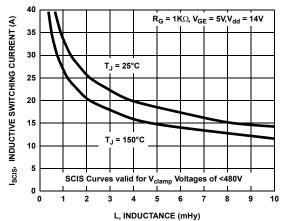
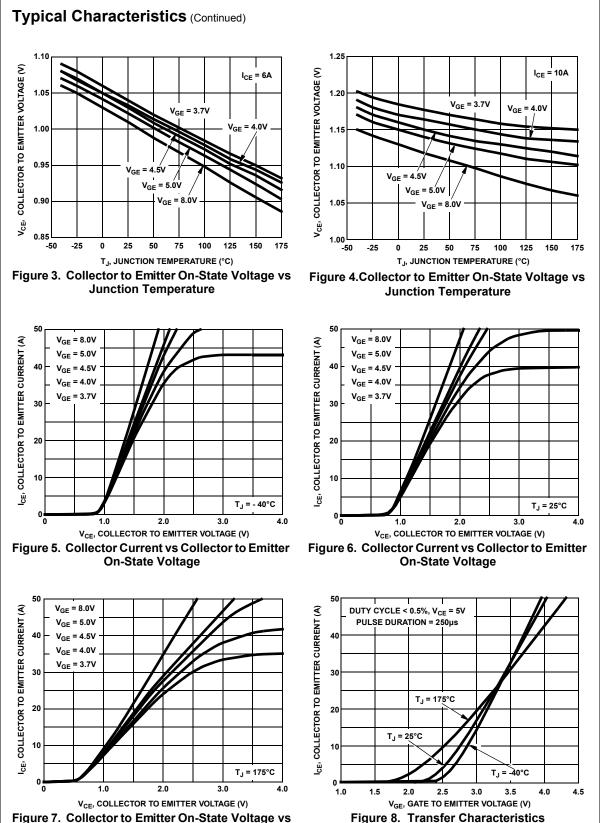
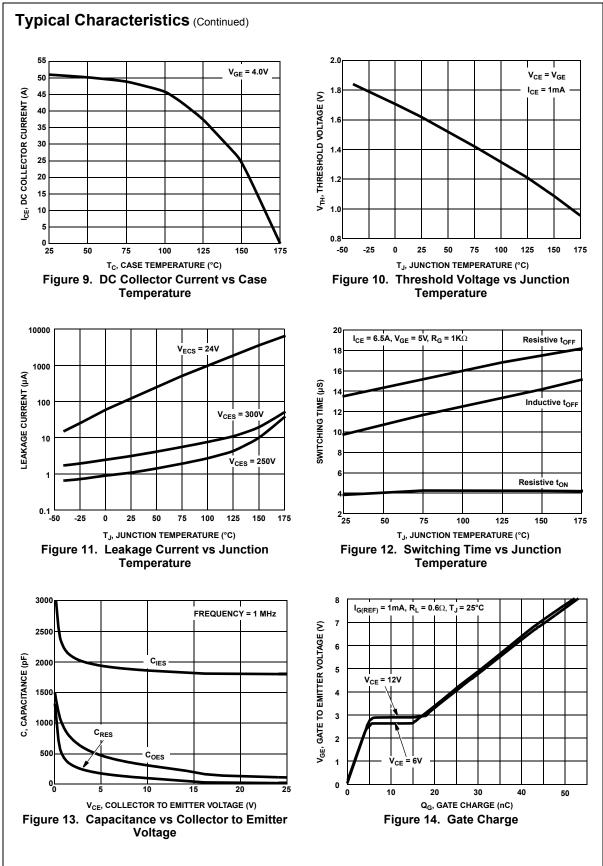
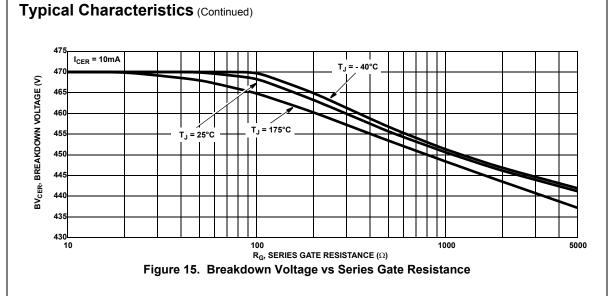


Figure 2. Self Clamped Inductive Switching Current vs Inductance



Collector Current





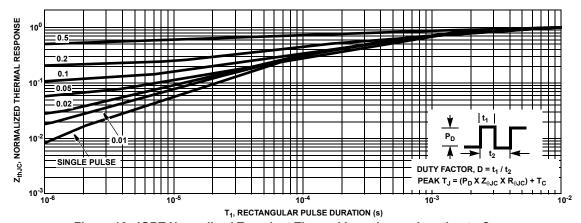


Figure 16. IGBT Normalized Transient Thermal Impedance, Junction to Case

Test Circuits and Waveforms

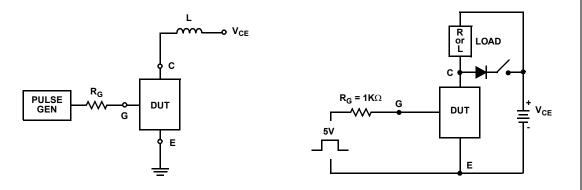
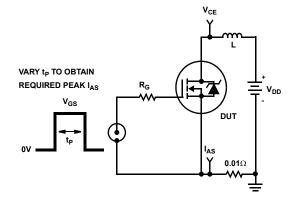


Figure 17. Inductive Switching Test Circuit

Figure 18. t_{ON} and t_{OFF} Switching Test Circuit

Test Circuits and Waveforms (Continued)





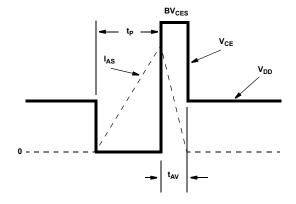


Figure 20. Energy Waveforms

SPICE Thermal Model JUNCTION REV 27 May 2005 ISL9V5045S3S / ISL9V5045S3 CTHERM1 th 6 82e-4 CTHERM2 6 5 105e-4 CTHERM3 5 4 12e-3 RTHERM1 CTHERM1 CTHERM4 4 3 33e-3 CTHERM5 3 2 55e-3 CTHERM6 2 tl 170e-3 RTHERM1 th 6 3e-3 RTHERM2 6 5 20e-3 RTHERM3 5 4 50e-3 RTHERM2 CTHERM2 RTHERM4 4 3 60e-3 RTHERM5 3 2 100e-3 RTHERM6 2 tl 127e-3 5 SABER Thermal Model SABER thermal model RTHERM3 CTHERM3 ISL9V5045S3S / ISL9V5045S3 template thermal model th tl thermal_c th, tl ctherm.ctherm1 th 6 = 82e-4 ctherm.ctherm2 6 5 = 105e-4 ctherm.ctherm3 5 4 = 12e-3 ctherm.ctherm4 4 3 = 33e-3 RTHERM4 CTHERM4 ctherm.ctherm5 3 2 = 55e-3 ctherm.ctherm6 2 tl = 170e-3 rtherm.rtherm1 th 6 = 3e-3 3 rtherm.rtherm2 6 5 = 20e-3 rtherm.rtherm354 = 50e-3rtherm.rtherm4 4 3 = 60e-3RTHERM5 CTHERM5 rtherm.rtherm5 3 2 = 100e-3 rtherm.rtherm6 2 tl = 127e-3 2 RTHERM6 CTHERM6

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CASE





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Definition of Terms

Deminition of Terms		
Datasheet Identification	Product Status	Definition
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